

Vishay Semiconductors

Silicon Rectifier Diodes, (Stud Version) 15 A



DO-203AB	(DO-5)
DU-ZUSAD ((DO-5)

PRODUCT SUMMARY			
I _{F(AV)}	15 A		
Package	DO-203AB (DO-5)		
Circuit configuration	Single diode		

FEATURES

- · Low thermal impedance
- High case temperature



- Excellent reliability
- · Maximum design flexibility
- Can be made to meet stringent military, aerospace and other high reliability requirements
- Material categorization: For definitions of compliance please see www.vishay.com/doc?99912

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
I _{F(AV)}		15 ⁽¹⁾	А	
	T _C	150 ⁽¹⁾	°C	
I _{FSM}	50 Hz	239	A	
	60 Hz	250 ⁽¹⁾		
I ² t	50 Hz	286	— A ² s	
	60 Hz	260		
$I^2\sqrt{t}$		3870	A ² √s	
V _{RRM}	Range	50 to 600	V	
T _J		-65 to 175	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C TO 175 °C) V	V_{RM} , MAXIMUM DIRECT REVERSE VOLTAGE ($T_J = -65 ^{\circ}\text{C}$ TO 175 $^{\circ}\text{C}$)			
VS-1N3208	50 ⁽¹⁾	50 ⁽¹⁾			
VS-1N3209	100 (1)	100 (1)			
VS-1N3210	200 (1)	200 ⁽¹⁾			
VS-1N3211	300 (1)	300 (1)			
VS-1N3212	400 (1)	400 (1)			
VS-1N3213	500 ⁽¹⁾	500 ⁽¹⁾			
VS-1N3214	600 ⁽¹⁾	600 ⁽¹⁾			

Notes

- (1) JEDEC registered values
- Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g. 1N3208R, 1N3209R

⁽¹⁾ JEDEC® registered values



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FORWARD CONDUCTION					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current at case temperature	I _{F(AV)}	180° sinusoidal conduction		15 ⁽¹⁾	A °C
	n-repetitive surge current Half cycle 50 Hz sine wave or 6 ms rectangular pulse Following any rated load condition and with V _{RRM}		239	A	
Maximum peak one cycle			250 ⁽¹⁾		
non-repetitive surge current		284	A		
		•	applied following surge = 0	297	
Maximum 12t fax fuaina	$t = 10 \text{ ms}$ With rated V_{RRM} applied	286			
Maximum I ² t for fusing	- l ² t	t = 8.3 ms	following surge, initial T _J = 150 °C	260	A ² s
Maximum I ² t for individual device fusing	- I-t	t = 10 ms	With V _{RRM} = 0 following surge, initial T _J = 150 °C	403	A-S
		t = 8.3 ms		368	
Maximum l ² √t for individual device fusing	I²√t (²)	t = 0.1 ms to 10 ms, V _{RRM} = 0 following surge		3870	A²√s
Maximum forward voltage drop	V_{FM}	I _{F(AV)} = 15 A (47.1 A peak), T _C = 150 °C		1.5 ⁽¹⁾	V
Maximum average reverse current	I _{R(AV)}	Maximum rated I _{F(AV)} and T _C = 150 °C		10 (1)	mA

Notes

- (1) JEDEC registered values
- (2) I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$

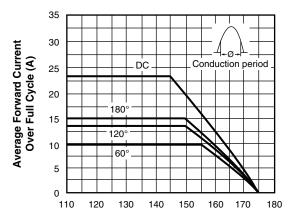
THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum junction operating and storage temperature range	T _J , T _{Stg}		-65 to 175 ⁽¹⁾	°C	
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	0.65	°C/W	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		
		Not lubricated thread, tighting on nut (2)	3.4	(30)	
Maximum allowable mounting torque		Lubricated thread, tighting on nut (2)	2.3	(20)	
(+0 %, -10 %)		Not lubricated thread, tighting on hexagon (3)	4.2	(37)	
		Lubricated thread, tighting on hexagon (3)	3.2	(28)	
Weight			28.5	g	
Weight			1	OZ.	
Case style		JEDEC	DO-203AB (DO-5)		

Notes

- (1) JEDEC registered values
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

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Maximum Allowable Case Temperature (°C)

Fig. 1 - Average Forward Current vs. Maximum Allowable Case Temperature

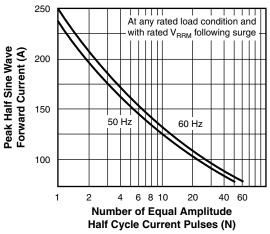
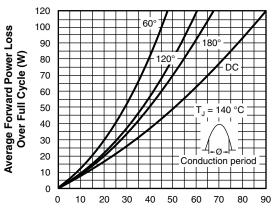
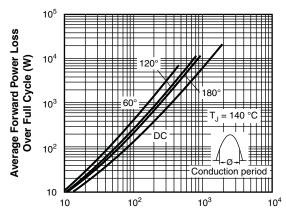


Fig. 2 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses



Average Forward Current Over Full Cycle (A)

Fig. 3 - Maximum Low Level Forward Power Loss vs. Average Forward Current



Average Forward Current Over Full Cycle (A)

Fig. 4 - Maximum High Level Forward Power Loss vs. Average Forward Current

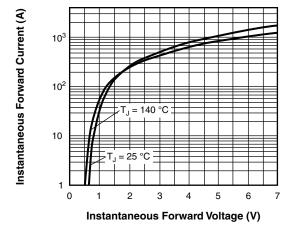


Fig. 5 - Maximum Forward Voltage vs. Forward Current

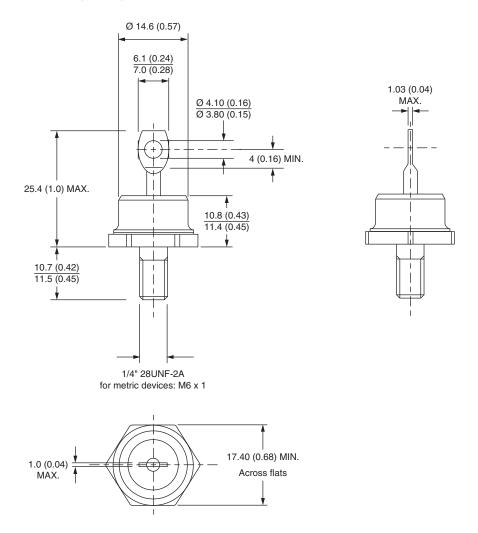
LINKS TO RELATED DOCUMENTS		
Dimensions	www.vishay.com/doc?95360	



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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)





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